

EL7202C/7212C/7222C

High Speed, Dual Channel Power MOSFET Drivers

Features

- Industry standard driver replacement
- Improved response times
- Matched rise and fall times
- Reduced clock skew
- Low output impedance
- Low input capacitance
- High noise immunity
- Improved clocking rate
- Low supply current
- Wide operating voltage range

Applications

- Clock/line drivers
- CCD Drivers
- Ultra-sound transducer drivers
- Power MOSFET drivers
- Switch mode power supplies
- Class D switching amplifiers
- Ultrasonic and RF generators
- Pulsed circuits

Ordering Information

 Part No.
 Temp. Range
 Pkg.
 Outline #

 EL7202CN
 -40°C to
 +85°C 8-Pin P-DIP
 MDP0031

 EL7202CS
 -40°C to
 +85°C 8-Pin SO
 MDP0027

 EL7212CN
 -40°C to
 +85°C 8-Pin SO
 MDP0027

 EL7212CS
 -40°C to
 +85°C 8-Pin SO
 MDP0027

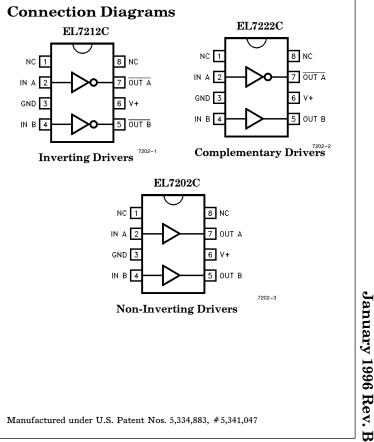
 EL7222CN
 -40°C to
 +85°C 8-Pin P-DIP
 MDP0031

 EL7222CN
 -40°C to
 +85°C 8-Pin SO
 MDP0031

 EL7222CS
 -40°C to
 +85°C 8-Pin SO
 MDP0027

General Description

The EL7202C/EL7212C/EL7222C ICs are matched dual-drivers ICs that improve the operation of the industry standard DS0026 clock drivers. The Elantec Versions are very high speed drivers capable of delivering peak currents of 2.0 amps into highly capacitive loads. The high speed performance is achieved by means of a proprietary "Turbo-Driver" circuit that speeds up input stages by tapping the wider voltage swing at the output. Improved speed and drive capability are enhanced by matched rise and fall delay times. These matched delays maintain the integrity of input-to-output pulse-widths to reduce timing errors and clock skew problems. This improved performance is accompanied by a 10 fold reduction in supply currents over bipolar drivers, yet without the delay time problems commonly associated with CMOS devices. Dynamic switching losses are minimized with non-overlapped drive techniques.



Note: All information contained in this data sheet has been carefully checked and is believed to be accurate as of the date of publication; however, this data sheet cannot be a "controlled document". Current revisions, if any, to these specifications are maintained at the factory and are available upon your request. We recommend checking the revision level before finalization of your design documentation.

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Absolute Maximum Ratings

Supply (V+ to Gnd)		Operating Junction Temperature	125°C
Input Pins	$-0.3V$ to $+0.3V$ above V $^+$	Power Dissipation	
Combined Peak Output Current	4A	SOIC	570 mW
Storage Temperature Range	-65° C to $+150^{\circ}$ C	PDIP	1050 mW
Ambient Operating Temperature	-40° C to $+85^{\circ}$ C		
Important Note:			

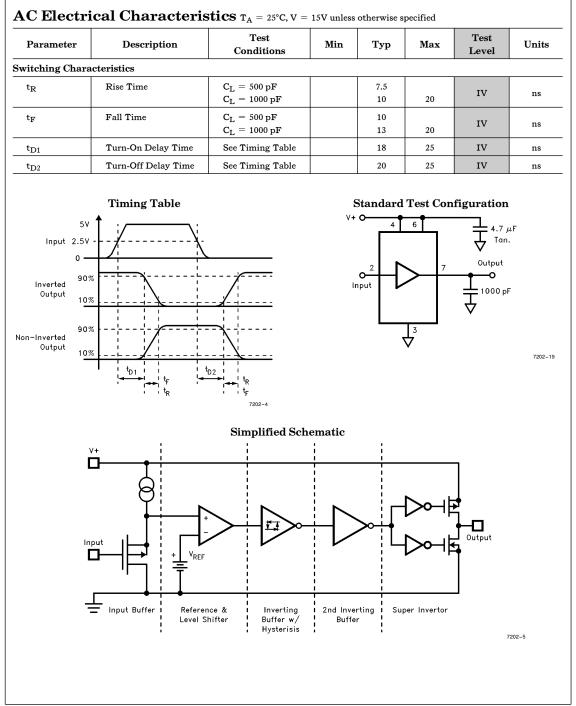
All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality inspection. Elantec performs most electrical tests using modern high-speed automatic test $equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore T_J=T_C=T_A.$

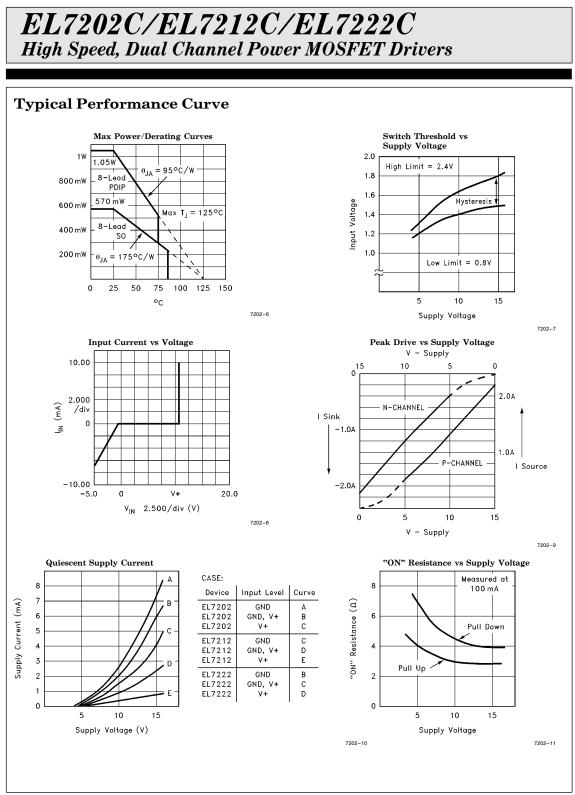
Test Level	Test Procedure
Ι	100% production tested and QA sample tested per QA test plan QCX0002.
II	100% production tested at $T_{\rm A}=25^{\circ}{\rm C}$ and QA sample tested at $T_{\rm A}=25^{\circ}{\rm C}$,
	T_{MAX} and T_{MIN} per QA test plan QCX0002.
III	QA sample tested per QA test plan QCX0002.
IV	Parameter is guaranteed (but not tested) by Design and Characterization Data.
v	Parameter is typical value at $T_A = 25^{\circ}C$ for information purposes only.

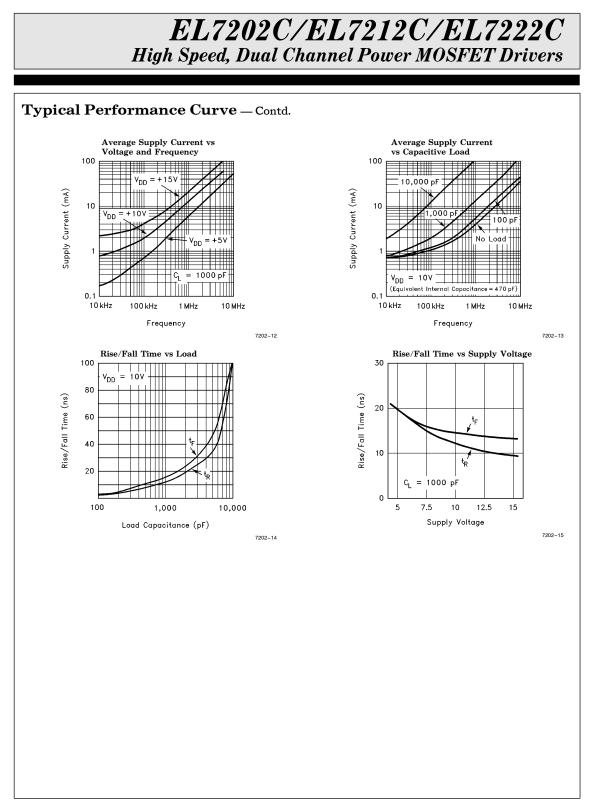
DC Electrical Characteristics $T_A = 25^{\circ}C$, V = 15V unless otherwise specified

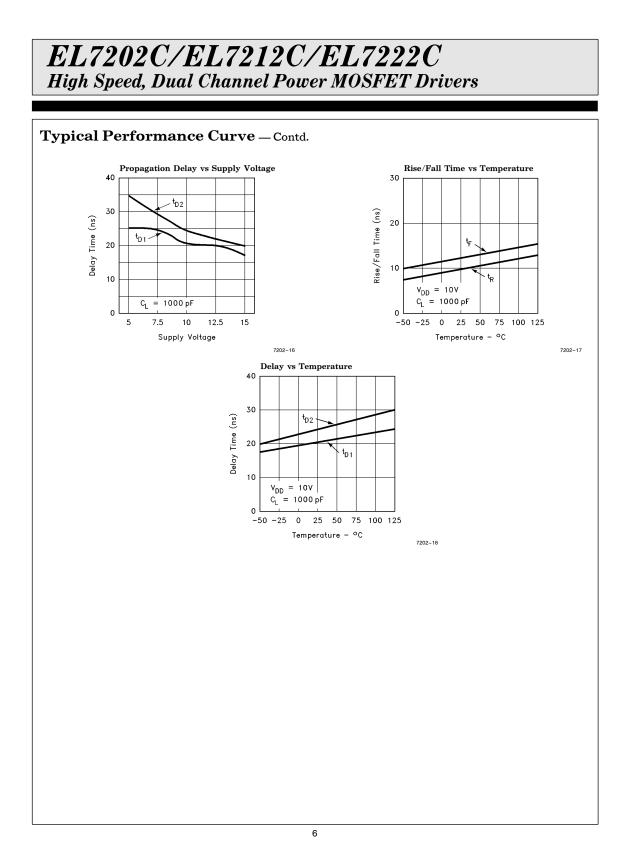
Parameter	Description	Test Conditions	Min	Тур	Max	Test Level	Units
Input			•				
VIH	Logic "1" Input Voltage		2.4			I	v
I _{IH}	Logic "1" Input Current	@V+		0.1	10	I	μΑ
V _{IL}	Logic "0" Input Voltage				0.8	I	v
I _{IL}	Logic "0" Input Current	@0V		0.1	10	I	μΑ
V _{HVS}	Input Hysteresis			0.3		v	v
Output	·	·	•				
R _{OH}	Pull-Up Resistance	$I_{OUT} = -100 \text{ mA}$		3	6	I	Ω
R _{OL}	Pull-Down Resistance	$I_{OUT} = +100 \text{ mA}$		4	6	I	Ω
I _{PK}	Peak Output Current	Source Sink		2 2		IV	A
I _{DC}	Continuous Output Current	Source/Sink	100			I	mA
Power Supply	•	•					
I _S	Power Supply Current	Inputs High/7202		4.5	7.5	I	
		Inputs High/7212		1	2.5	I	mA
		Inputs High/7222		2.5	5.0	I	
VS	Operating Voltage		4.5		15	I	v

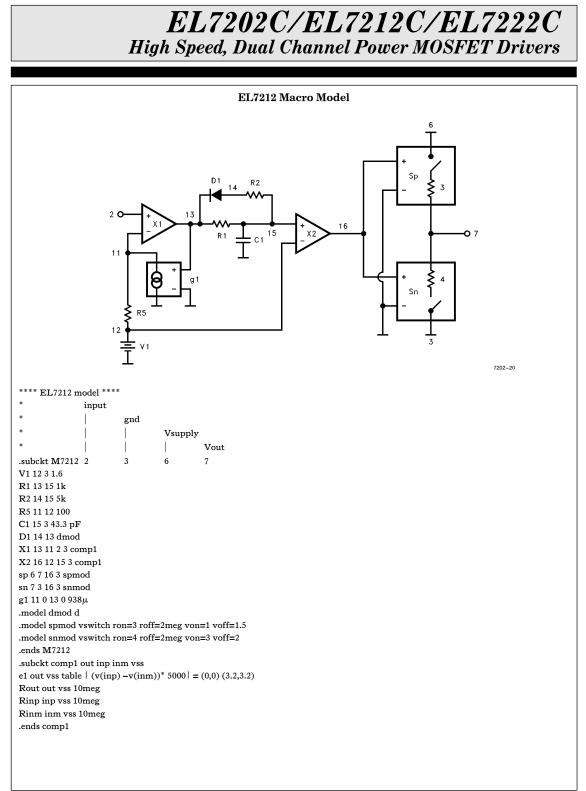
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General Disclaimer

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